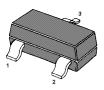
# HIGH SPEED DOUBLE SWITCHING DIODE

## Features

- Small package
- Low forward voltage
- Fast reverse recovery time
- Small total capacitance

### Applications

• Ultra high speed switching application



Marking Code: A1 SOT-23 Plastic Package

### Absolute Maximum Ratings (T<sub>a</sub> = 25 °C)

Parameter			Symbol	Value	Unit
Peak Repetitive Reverse Voltage		V <sub>RRM</sub>	85	V	
Continuous Reverse Voltage			V <sub>R</sub>	75	V
Forward Current (DC)	Single Diode Loaded Double Diode Loaded		I <sub>F</sub>	215 125	mA
Repetitive Peak Forward Curre	ent		I <sub>FRM</sub>	450	mA
Non-Repetitive Peak Forward Current		at t = 1 µs		4	А
		at t = 1 ms	I <sub>FSM</sub>	1	А
		at t = 1 s		0.5	А
Power Dissipation			P <sub>tot</sub>	250	mW
Operating Junction Temperatu	re Range		TJ	150	°C
Storage Temperature Range			Ts	- 65 to + 150	°C

### Characteristics at T<sub>a</sub> = 25 °C

Parameter	Symbol	Max.	Unit
Forward Voltage			
at I <sub>F</sub> = 1 mA	V <sub>F</sub>	715	mV
at I <sub>F</sub> = 10 mA	V <sub>F</sub>	855	mV
at I <sub>F</sub> = 50 mA	V <sub>F</sub>	1	V
at I <sub>F</sub> = 150 mA	V <sub>F</sub>	1.25	V
Reverse Current			
at V <sub>R</sub> = 25 V	I <sub>R</sub>	30	nA
at $V_R$ = 75 V	I <sub>R</sub>	1	μA
at V <sub>R</sub> = 25 V, T <sub>J</sub> = 150 °C	I <sub>R</sub>	30	μA
at V <sub>R</sub> = 75 V, T <sub>J</sub> = 150 °C	I <sub>R</sub>	50	μA
Diode Capacitance	C <sub>d</sub>	2	рЕ
at f = 1 MHz	Cd	2	pF
Reverse Recovery Time	4	4	20
at $I_{\rm F} = I_{\rm R} = 10$ mA, $R_{\rm I} = 100 \Omega$	t <sub>rr</sub>	4	ns

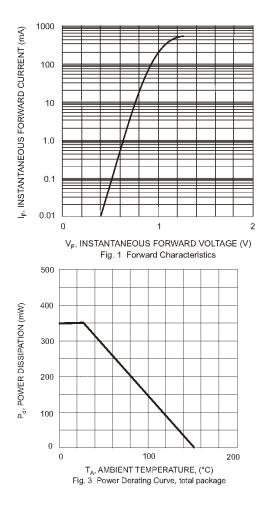


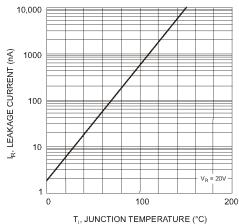
**SEMTECH ELECTRONICS LTD.** (Subsidiary of Sino-Tech International Holdings Limited, a company

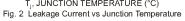
listed on the Hong Kong Stock Exchange, Stock Code: 724)



Dated : 22/01/2008













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